SN74ALVCH373 OCTAL TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS

SCES116H-JULY 1997-REVISED OCTOBER 2004

FEATURES

- Operates From 1.65 V to 3.6 V
- Max t_{pd} of 3.3 ns at 3.3 V
- ±24-mA Output Drive at 3.3 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DGV, DW, OR PW PACKAGE (TOP VIEW) OE [20 ∏ V_{CC} 1Q 🛮 2 19 **| 8Q** 1D 18 N 8D 3 17 | 7D 2D 2Q 16**∏** 7Q П 5 3Q **∏** 6 15 **∏** 6Q 3D 14 🛮 6D **П**7 П 8 4D 13 **[**] 5D 12 **∏** 5Q 4Q 9 **GND** 11 ∏ LE

DESCRIPTION/ORDERING INFORMATION

This octal transparent D-type latch is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH373 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

ORDERING INFORMATION

T _A	PACKAG	E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube	SN74ALVCH373DW	ALVCH373
	30IC - DW	Tape and reel	SN74ALVCH373DWR	ALVON3/3
-40°C to 85°C	TSSOP - PW	Tape and reel	SN74ALVCH373PWR	VB373
-40 C to 65 C	TVSOP - DGV	Tape and reel	SN74ALVCH373DGVR	VB373
	VFBGA - GQN	Tana and real	SN74ALVCH373GQNR	VD272
	VFBGA - ZQN (Pb-free)	Tape and reel	SN74ALVCH373ZQNR	VB373

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

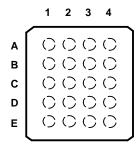


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GQN OR ZQN PACKAGE (TOP VIEW)



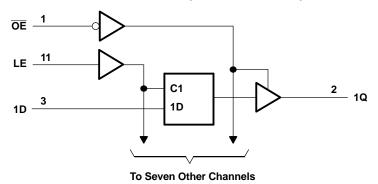
TERMINAL ASSIGNMENTS

	1	2	3	4
Α	1Q	ŌĒ	V _{CC}	8Q
В	2D	7D	1D	8D
С	3Q	2Q	6Q	7Q
D	4D	5D	3D	6D
E	GND	4Q	LE	5Q

FUNCTION TABLE (each latch)

	INPUTS							
OE	LE	D	Q					
L	Н	Н	Н					
L	Н	L	L					
L	L	X	Q ₀					
Н	Χ	X	Z					

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the DGV, DW, and PW packages.



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ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range ⁽²⁾		-0.5	4.6	V	
Vo	Output voltage range (2)(3)		-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
Io	Continuous output current	1 2				
	Continuous current through V_{CC} or GND			±100	mA	
		DGV package		92		
0	Deales as the small instantial and (4)	DW package		58		
θ_{JA}	Package thermal impedance ⁽⁴⁾	GQN/ZQN package		78	°C/W	
		PW package		83		
T _{stg}	Storage temperature range		-65	150	°C	

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage		1.65	3.6	V
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V
		V _{CC} = 2.7 V to 3.6 V	2		
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V_{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7	V
		V _{CC} = 2.7 V to 3.6 V		0.8	
VI	Input voltage	·	0	V _{CC}	V
Vo	Output voltage		0	V_{CC}	V
		V _{CC} = 1.65 V		-4	
	High lavel autout august	V _{CC} = 2.3 V		-12	A
I _{OH}	High-level output current	V _{CC} = 2.7 V	-12		mA
	Output voltage	V _{CC} = 3 V		-24	
		V _{CC} = 1.65 V		4	
	Laur laural autout aumant	V _{CC} = 2.3 V		12	mA
l _{OL}	Low-level output current	V _{CC} = 2.7 V		12	
		V _{CC} = 3 V		24	
Δt/Δν	Input transition rise or fall rate	fall rate		5	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ This value is limited to 4.6 V maximum.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

SN74ALVCH373 **OCTAL TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS**





ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

F	PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP(1) MAX	UNIT			
		I _{OH} = -100 μA	1.65 V to 3.6 V	V _{CC} - 0.2					
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2					
		$I_{OH} = -6 \text{ mA}$	2.3 V	2					
V_{OH}			2.3 V	1.7		V			
		I _{OH} = -12 mA	2.7 V	2.2					
			3 V	2.4					
VOH VOL I I I I I(hold) IOZ ICC ΔICC C: Control i		$I_{OH} = -24 \text{ mA}$	3 V	2					
V_{OL}	I _{OL} = 100 μA	1.65 V to 3.6 V		0.2					
	I _{OL} = 4 mA	1.65 V		0.45					
	I _{OL} = 6 mA	2.3 V		0.4	\ /				
	1 40 4	2.3 V		0.7	V				
	1	I _{OL} = 12 mA	2.7 V		0.4				
		I _{OL} = 24 mA	3 V		0.55				
I _I		$V_{I} = V_{CC}$ or GND	3.6 V		±5	μΑ			
	$V_{I} = V_{CC} \text{ or GND}$ $V_{I} = 0.58 \text{ V}$ $V_{I} = 1.07 \text{ V}$	V _I = 0.58 V	1.65 V	25					
		V _I = 1.07 V	1.65 V	-25					
	V _I = 0.7 V	2.3 V	45						
I _{I(hold)}		V _I = 1.7 V	2.3 V	-45		μΑ			
, ,		V _I = 0.8 V	3 V	75					
		V _I = 2 V	3 V	-75					
		$V_1 = 0 \text{ to } 3.6 \text{ V}^{(2)}$	3.6 V		±500				
l _{OZ}		$V_O = V_{CC}$ or GND	3.6 V		±10	μΑ			
I _{CC}		$V_1 = V_{CC}$ or GND, $I_O = 0$	3.6 V		20	μΑ			
		One input at V _{CC} - 0.6 V, Other inputs at V _{CC} or GND	3 V to 3.6 V		750	μΑ			
	Control inputs	V V STOND	0.01/	4.5	5	pF			
C _i	Data inputs	$V_{I} = V_{CC}$ or GND	3.3 V	5					
C _o	Outputs	$V_O = V_{CC}$ or GND	3.3 V	7.5	5	pF			

TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		V _{CC} = 1.8 V		V _{CC} = 1 ± 0.2	2.5 V 2 V	V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{w}	Pulse duration, LE high	3.8		3.3		3.3		3.3		ns
t_{su}	Setup time, data before LE↓	1.3		0.5		0.5		0.5		ns
t _h	Hold time, data after LE↓	0.5		1.3		1.7		1.2		ns

⁽¹⁾ All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to





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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V_{CC} = 2.5 V \pm 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INPOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
4	D	Q	1.7	6.3	1	4		4	1	3.6	20
^L pd	LE	Q	2	6.1	1	3.8		3.7	1	3.3	ns
t _{en}	ŌĒ	Q	3.4	8.3	1.9	5.4		5.4	1.6	4.8	ns
t _{dis}	ŌĒ	Q	1.6	7	1	4.4		4.4	1	4.4	ns

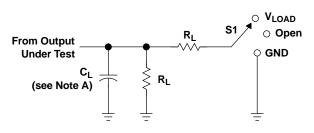
OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}C$

	PARAMETE	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT		
Power dissipation		Outputs enabled	C 0 f 10 MHz	31	33	37	~F	
C_{pd}	capacitance per latch	Outputs disabled	$C_L = 0$, $f = 10 MHz$	7	7	9	pF	



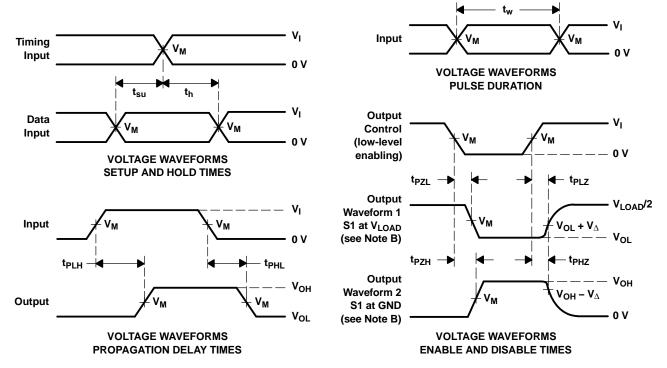
PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

Voc	IN	PUT	V	v	•	В	V
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	$V_{\!\scriptscriptstyle \Delta}$
1.8 V ± 0.15 V	V _{CC}	≤ 2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{O} = 50 \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
74ALVCH373DGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples
74ALVCH373DGVRG4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples
SN74ALVCH373DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples
SN74ALVCH373DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH373	Samples
SN74ALVCH373DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH373	Samples
SN74ALVCH373DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH373	Samples
SN74ALVCH373DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH373	Samples
SN74ALVCH373DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH373	Samples
SN74ALVCH373DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH373	Samples
SN74ALVCH373PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples
SN74ALVCH373PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples
SN74ALVCH373PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples
SN74ALVCH373ZQNR	ACTIVE	BGA MICROSTAR JUNIOR	ZQN	20	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VB373	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

11-Apr-2013

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All difficults are normal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH373DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74ALVCH373DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ALVCH373PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74ALVCH373ZQNR	BGA MI CROSTA R JUNI OR	ZQN	20	1000	330.0	12.4	3.3	4.3	1.6	8.0	12.0	Q1

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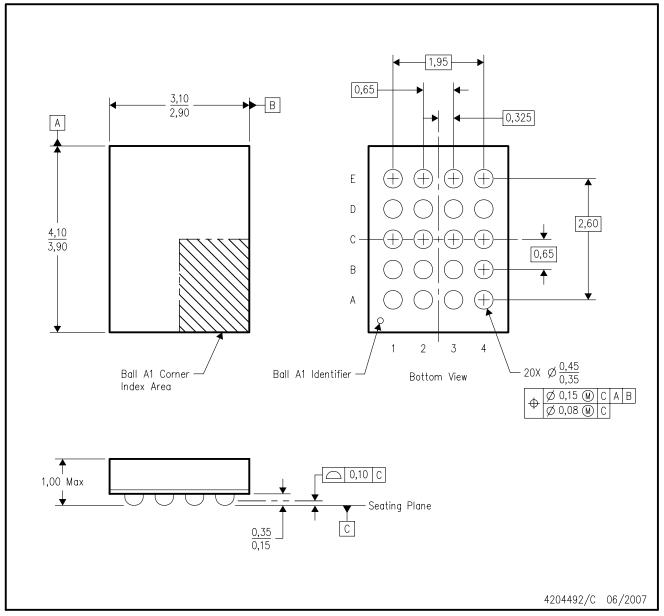


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH373DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74ALVCH373DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ALVCH373PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74ALVCH373ZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	338.1	338.1	20.6

ZQN (R-PBGA-N20)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BC-2.
- D. This package is lead-free. Refer to the 20 GQN package (drawing 4200704) for tin-lead (SnPb).



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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